

MA4PK2004

MA4PK3004

2000 Volt & 3000 Volt PIN Diodes MA4PK200X & MA4PK300X

V10

Features

- Reverse Voltage up to 3000 Volts
- 25 Ampere Current Rating
- Designed for HF, Multi-Throw Kilowatt Switches
- Low Loss, Low Distortion
- Rugged, Hermetically Sealed Packaging
- Convenient Solder Lug Attachment
- Non Magnetic to 3 Tesla for MRI Applications
- **RoHS Compliant**

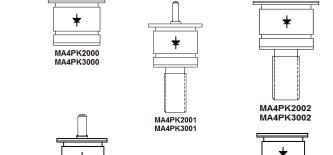
Description

M/A-COM Technology Solutions KILOVOLT™ PIN diode series utilize modern semiconductor packaging technology that assures low loss, low distortion, and reliable performance in multi-kilowatt switch applications at frequencies as low as 1 MHz. The PIN chips employed have low resistance, high power dissipation and very high stand-off voltage capability. KILOVOLT™ PIN diodes employ ultra high resistively, long carrier lifetime, float zone material onto which P+ and N+ regions are deposited using an epitaxial process designed by M/A-COM Technology Solutions for high voltage PIN diodes. This process results in better preservation of the carrier lifetime and superior layer to layer interface when compared to a conventional double diffused process. The processing of the I-region width is tightly controlled using modern lapping techniques. KILOVOLT™ PIN diode chips utilize M/A-COM Technology Solutions proprietary Cermachip™ glass passivation. The hard glass covers all exposed junction and intrinsic surfaces. This results in a hermetically sealed, passivated chip that has been used in many high reliability military and commercial programs.

Applications

The KILOVOLT™ PIN diode series is designed for use as high power switching elements in multi-kilowatt HF and VHF applications. These PIN diodes have been extensively characterized for their electrical and thermal properties to assure predictable, low loss, high power handling and low distortion performance. Some typical applications are as follows:

- Filter Switches
- Antenna Couplers
- Power Amplifier By-pass Switches
- **MRI Switches**



Package Outlines

Packaging

MA4PK2003

MA4PK3003

The metal-ceramic packages were developed specifically for the KILOVOLT™ PIN diode series. The packages are designed to withstand extremely high voltages and currents. The packages meet the environmental requirements of MIL-STD-202 and MIL-STD750. The PIN diode chip is bonded to the package and the anode strap is bonded to the chip at temperatures exceeding 300°C. The anode strap has a unique, large cross-sectional area allowing for high current carrying capability. The packages are sealed using a projection welding technique in an inert environment. KILOVOLT™ PIN diodes are available with a solder lug on the anode electrode to allow for a convenient and reliable wrap-around

Diode Part Numbers & Package Style

2000 Volts	3000 Volts	Package Style
MA4PK2000	MA4PK3000	Pill
MA4PK2001	MA4PK3001	Threaded Stud & Solder Lug
MA4PK2002	MA4PK3002	Threaded Stud Only
MA4PK2003	MA4PK3003	Insulated Threaded Stud & Solder Lug
MA4PK2004	MA4PK3004	Insulated Threaded Stud Only

- ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions
- North America Tel: 800.366.2266 Europe Tel: +353.21.244.6400
 - India Tel: +91.80.43537383
- · China Tel: +86.21.2407.1588



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ABSOLUTE MAXIMUM	RATINGS	MAXIMUM POWER DISSIPATION @ T _{CASE} = 25°C		
Operating and Storage Temp.	-65°C to +175°C	MA4PK2001 MA4PK2002	50 Watts	
Installation Temperature	250°C/30 Seconds	MA4PK2003 MA4PK2004	37.5 Watts	
Instantaneous Reverse Voltage	Voltage Rating	MA4PK3001 MA4PK3002	75 Watts	
Forward Current (RF and DC)	25 Amperes	MA4PK3003 MA4PK3004	50 Watts	
ESD	Class 1C, HBM			

Electrical Specifications¹ @ T_A = 25°C

PARAMETER	CONDITION	MA4PK2000 Series	MA4PK3000 Series
Reverse Voltage (Max) V _R	10 μΑ	2000 Volts	3000 Volts
Series Resistance (Max) R _S	F = 4 MHz, I = 0.5 A	0.20 Ω	0.25 Ω
Series Resistance (Typ.) R _S	F = 1.0 -100 MHz, I = 0.5 A	0.10 Ω	0.15 Ω
Total Capacitance (Max) C _T	F = 1 MHz, V = 100 V	3.2 pF	4.0 pF
Parallel Resistance (Typ.) R _P	F =100 MHz, V = 0 V	5Κ Ω	10Κ Ω
Carrier Lifetime (Min) T _L	IF = 10 mA	30 µs	65 µs
Forward Voltage (Max) V _F	IF = 1 A	1.2 V	1.2 V
Thermal Resistance (Max) Ø		3°C/W (Stud) 4°C/W (Ins Stud)	2°C/W (Stud) 3°C/W (Ins Stud)
I-Region Width (Nom)		200 μm	325 μm

^{1.} Specifications Subject to Change Without Notice.

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Visit www.macomtech.com for additional data sheets and product information.

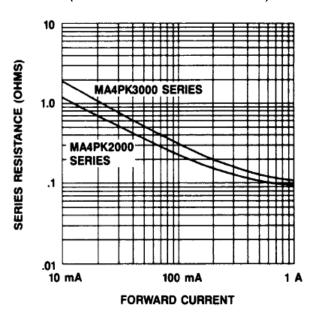


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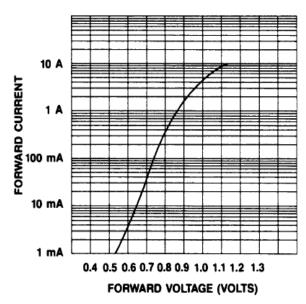
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Typical Performance Curves @ +25°C

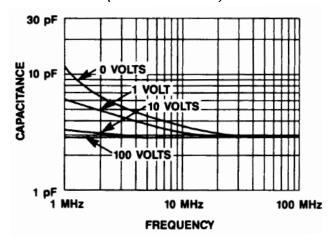
Series Resistance vs. Current @ 100MHz (MA4PK2000 & MA4PK3000 Series)



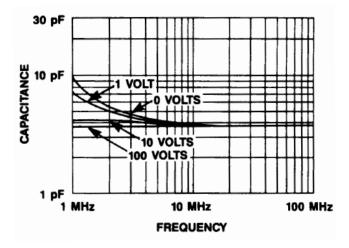
Forward Voltage vs. Forward Current (MA4PK2000 & MA4PK3000 Series)



Capacitance vs. Frequency & Reverse Voltage (MA4PK2000 Series)



Capacitance vs. Frequency & Reverse Voltage (MA4PK3000 Series)



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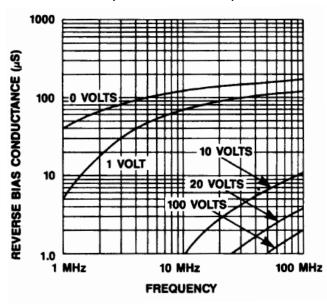


2000 Volt & 3000 Volt PIN Diodes MA4PK200X & MA4PK300X

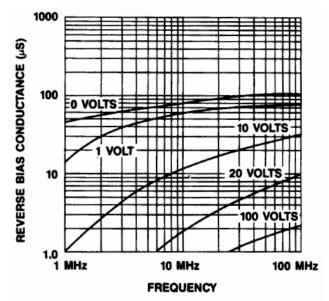
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Typical Performance Curves @ 25°C

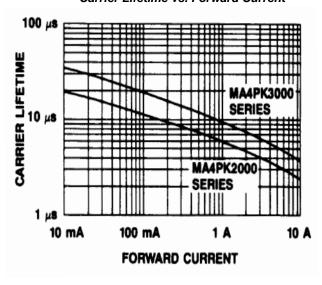
Conductance vs. Frequency & Reverse Voltage (MA4PK2000 SERIES)



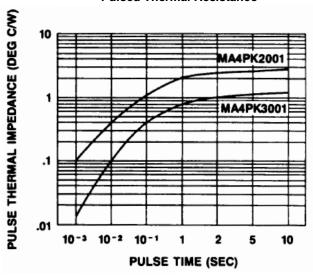
Conductance vs. Frequency & Reverse Voltage (MA4PK3000 SERIES)



Carrier Lifetime vs. Forward Current



Pulsed Thermal Resistance



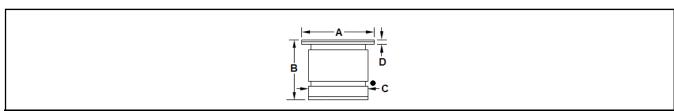
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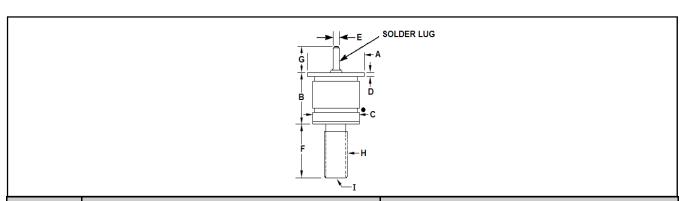
2000 Volt & 3000 Volt PIN Diodes MA4PK200X & MA4PK300X

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Case Styles • Black Dot Denotes Cathode



	MA4PK2000 CASE STYLE 1027				MA4PK3000 CASE STYLE 1073			
	INC	INCHES MILLIMETERS		INC	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX
Α	0.304	0.316	7.72	8.02	0.468	0.485	11.90	12.30
В	0.286	0.292	7.26	7.42	0.387	0.411	9.83	10.40
С	0.245	0.255	6.22	6.48	0.390	0.400	9.90	10.10
D	0.023	0.031	0.58	0.79	0.028	0.042	0.71	1.06
	$C_P = .$	45 pF	L _S =	2 nH	$C_P = 0$	75 pF	L _S =	3 nH



DIM	MA4PK2001 CASE STYLE 1082				MA4PK3001 CASE STYLE 1084			
DIM	INC	HES	MILLIN	IETERS	INC	HES	MILLIN	IETERS
	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX
Α	0.304	0.316	7.72	8.02	0.468	0.485	11.90	12.30
В	0.286	0.292	7.26	7.42	0.387	0.411	9.83	10.40
С	0.245	0.255	6.22	6.48	0.390	0.400	9.90	10.10
D	0.023	0.031	0.58	0.79	0.028	0.042	0.71	1.06
E	0.060	0.065	1.52	1.65	0.060	0.065	1.52	1.65
F	0.281	0.305	7.14	7.75	0.425	0.445	10.80	11.30
G	0.190	0.205	4.83	5.21	0.190	0.205	4.83	5.21
Н		6-40 UNF-3A				10-32 l	JNF-2A	
ļ	.072 SPLINE X .070 DP				0.50 SLOT	X .060 DP		
	C _P = .	.45 pF	L _S =	2 nH	C _P =	.75 pF	L _S =	3 nH

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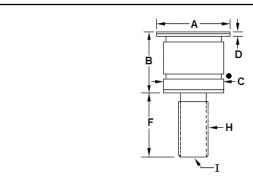
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2000 Volt & 3000 Volt PIN Diodes MA4PK200X & MA4PK300X

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Case Styles • Black Dot Denotes Cathode



		MA4P CASE ST				MA4P CASE ST		
DIM	INC	HES	MILLIN	IETERS	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX
А	0.304	0.316	7.72	8.02	0.468	0.485	11.90	12.30
В	0.286	0.292	7.26	7.42	0.387	0.411	9.83	10.40
С	0.245	0.255	6.22	6.48	0.390	0.400	9.90	10.10
D	0.023	0.031	0.58	0.79	0.028	0.042	0.71	1.06
F	0.281	0.305	7.14	7.75	0.425	0.445	10.80	11.30
Н	6-40 UNF-3A				10-32 L	JNF-2A		
I	.072 SPLINE X .070 DP				0.50 SLOT	X .060 DP		
	C _P =	45 pF	L _S =	2 nH	C _P =	.75 pF	L _S =	3 nH

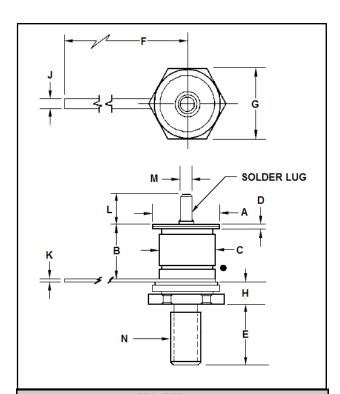
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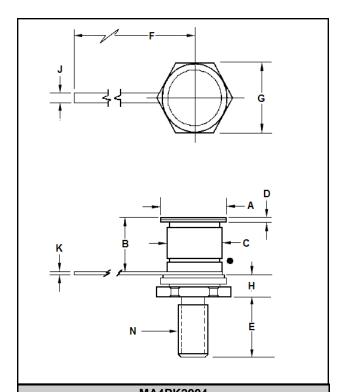
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Case Styles ● Black Dot Denotes Cathode



MA4PK2003								
	CASE STYLE 1080							
DIM	INC	HES	MILLIM	ETERS				
DIN	MIN	MAX	MIN	MAX				
Α	.304	.316	7.72	8.02				
В	.254	.270	6.45	6.86				
С	.245	.255	6.22	6.48				
D	.023	.031	0.58	0.79				
Е	.221	.252	5.61	6.40				
F	.780	.790	19.8	20.1				
G	.245	.255	6.22	6.48				
Η	.128	.137	3.25	3.48				
J	.120	.130	3.05	3.30				
K	.007	.009	0.18	0.23				
L	.190	.205	4.83	5.21				
М	.060	.065	1.52	1.65				
N	6-32 UNF-3A							
C_{GND}	= 1.1Pf	$C_P = .45 Pf$	L _S =	2 nH				



MA4PK2004						
	CAS	SE STYLE 1	038			
DIM	INC	HES	MILLIM	ETERS		
DIIVI	MIN	MAX	MIN	MAX		
Α	.304	.316	7.72	8.02		
В	.254	.270	6.45	6.86		
С	.245	.255	6.22	6.48		
D	.023	.031	0.58	0.79		
Е	.221	.252	5.61	6.40		
F	.780	.790	19.8	20.1		
G	.245	.255	6.22	6.48		
Н	.128	.137	3.25	3.48		
J	.120	.130	3.05	3.30		
K	.007	.009	0.18	0.23		
N	·	6-32 UNF-3A				
C_{GND}	= 1.1Pf	$C_P = .45 Pf$	L _S =	2 nH		

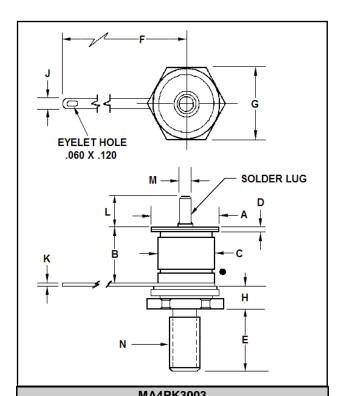
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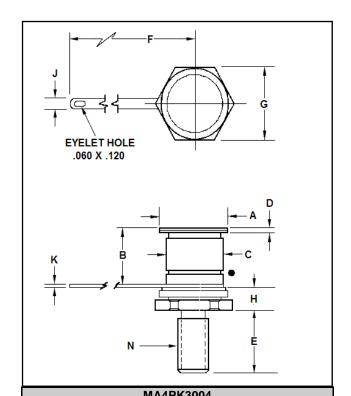
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Case Styles ● Black Dot Denotes Cathode



MA4PK3003							
CASE STYLE 1085							
DIM	INC	HES	MILLIMETERS				
DIIVI	MIN	MAX	MIN	MAX			
Α	.468	.485	11.9	12.3			
В	.385	.410	9.8	10.4			
С	.390	.400	9.90	10.1			
D	.030	.045	0.76	1.14			
E	.422	.452	10.72	11.48			
F	.805	.820	20.45	20.83			
G	.490	.500	12.45	12.70			
Н	.155	.175	3.94	4.45			
J	.120	.130	3.05	3.30			
K	.022	.026	.559	.660			
L	.190	.205	4.83	5.21			
М	.060	.065	1.52	1.65			
N		10-32 UNF-2A					
CGNE	= 1 1Pf	C _P = 75 Pf	s =	3 nH			



	CASE STYLE 1075						
		HES	MILLIM	ETERS			
DIM	MIN	MAX	MIN	MAX			
Α	.468	.485	11.9	12.3			
В	.385	.410	9.8	10.4			
С	.390	.400	9.90	10.1			
D	.030	.045	0.76	1.14			
E	.422	.452	10.72	11.48			
F	.805	.820	20.45	20.83			
G	.490	.500	12.45	12.70			
Н	.155	.175	3.94	4.45			
J	.120	.130	3.05	3.30			
K	.022	.026	.559	.660			
N		10-32 L	JNF-2A				
C _{GND}	= 1.1Pf	C _P = .75 Pf	L _S =	3 nH			

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